Field Stop Trench IGBT

40 A, 650 V

AFGHL40T65SQ

Using the novel field stop 4th generation high speed IGBT technology. AFGHL40T65SQ which is AEC Q101 qualified offers the optimum performance for both hard and soft switching topology in automotive application. It is a stand−alone IGBT.

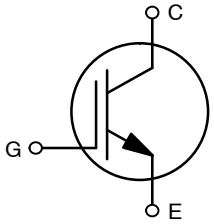
Features

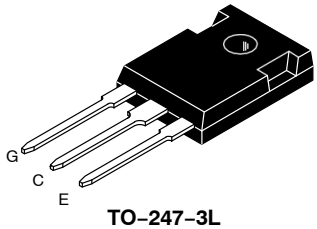
- AEC−Q101 Qualified
- Maximum Junction Temperature: T_J = 175°C
- Positive Temperature Co−efficient for Easy Parallel Operating
- High Current Capability
- Low Saturation Voltage: $V_{CE(Sat)}$ = 1.6 V (Typ.) @ I_C = 40 A
- 100% of the Parts are Tested for I_{LM} (Note 2)
- Fast Switching
- Tight Parameter Distribution
- RoHS Compliant

Typical Applications

- Automotive HEV−EV Onboard Chargers
- Automotive HEV−EV DC−DC Converters
- Totem Pole Bridgeless PFC
- PTC

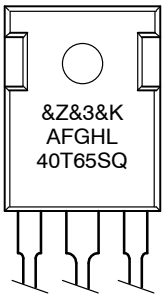
40 A, 650 V
V_{CESat} = 1.6 V





TO−247−3L
CASE 340CX

MARKING DIAGRAM



&Z = Assembly Plant Code
&3 = 3−Digit Date Code
&K = 2−Digit Lot Traceability Code
AFGHL40T65SQ = Specific Device Code

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector−to−Emitter Voltage	V_{CES}	650	V
Gate−to−Emitter Voltage Transient Gate−to−Emitter Voltage	V_{GES}	±20 ±30	V
Collector Current (Note 1) @ T_C = 25°C @ T_C = 100°C	I_C	80 40	A
Pulsed Collector Current (Note 2)	I_{LM}	160	A
Pulsed Collector Current (Note 3)	I_{CM}	160	A
Maximum Power Dissipation @ T_C = 25°C @ T_C = 100°C	P_D	239 119	W
Operating Junction / Storage Temperature Range	T_J, T_{STG}	−55 to +175	°C
Maximum Lead Temp. for Soldering Purposes, 1/8″ from case for 5 seconds	T_L	300	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Value limit by bond wire
2. V_{CC} = 400 V, V_{GE} = 15 V, I_C = 160 A, R_G = 15 Ω, Inductive Load
3. Repetitive Rating: pulse width limited by max. Junction temperature

ORDERING INFORMATION

Device	Package	Shipping
AFGHL40T65SQ	TO−247−3L	30 Units / Rail

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THERMAL CHARACTERISTICS

Rating	Symbol	Value	Unit
Thermal resistance junction−to−case, for IGBT	$R_{\theta JC}$	0.63	°C/W
Thermal resistance junction−to−ambient	$R_{\theta JA}$	40	°C/W

ELECTRICAL CHARACTERISTICS (T_J = 25°C unless otherwise noted)

Parameter	Test Conditions	Symbol	Min	Typ	Max	Unit
OFF CHARACTERISTICS						
Collector−emitter breakdown voltage, gate−emitter short−circuited	V_{GE} = 0 V, I_C = 1 mA	BV_{CES}	650	–	–	V
Temperature Coefficient of Breakdown Voltage	V_{GE} = 0 V, I_C = 1 mA	$\frac{\Delta BV_{CES}}{\Delta T_J}$	–	0.6	–	V/°C
Collector−emitter cut−off current, gate−emitter short−circuited	V_{GE} = 0 V, V_{CE} = 650 V	I_{CES}	–	–	250	μA
Gate leakage current, collector−emitter short−circuited	V_{GE} = 20 V, V_{CE} = 0 V	I_{GES}	–	–	±400	nA
ON CHARACTERISTICS						
Gate−emitter threshold voltage	V_{GE} = V_{CE}, I_C = 40 mA	$V_{GE(th)}$	3.4	4.9	6.4	V
Collector−emitter saturation voltage	V_{GE} = 15 V, I_C = 40 A V_{GE} = 15 V, I_C = 40 A, T_J = 175°C	$V_{CE(sat)}$	– –	1.6 1.95	2.1 –	V
DYNAMIC CHARACTERISTICS						
Input capacitance	V_{CE} = 30 V, V_{GE} = 0 V, f = 1 MHz	C_{ies}	–	2312	–	pF
Output capacitance		C_{oes}	–	30	–	
Reverse transfer capacitance		C_{res}	–	8	–	
Gate charge total	V_{CE} = 400 V, I_C = 40 A, V_{GE} = 15 V	Q_g	–	68	–	nC
Gate−to−emitter charge		Q_{ge}	–	13	–	
Gate−to−collector charge		Q_{gc}	–	16	–	
SWITCHING CHARACTERISTICS, INDUCTIVE LOAD						
Turn−on delay time	T_C = 25°C, V_{CC} = 400 V, I_C = 20 A, R_G = 6 Ω, V_{GE} = 15 V, Inductive Load, FWD: AFGHL40T65SQD	$t_{d(on)}$	–	15	–	ns
Rise time		t_r	–	10	–	
Turn−off delay time		$t_{d(off)}$	–	70	–	
Fall time		t_f	–	3	–	
Turn−on switching loss		E_{on}	–	0.25	–	mJ
Turn−off switching loss		E_{off}	–	0.09	–	
Total switching loss		E_{ts}	–	0.34	–	
Turn−on delay time	T_C = 25°C, V_{CC} = 400 V, I_C = 40 A, R_G = 6 Ω, V_{GE} = 15 V, Inductive Load, FWD: AFGHL40T65SQD	$t_{d(on)}$	–	17	–	ns
Rise time		t_r	–	22	–	
Turn−off delay time		$t_{d(off)}$	–	67	–	
Fall time		t_f	–	31	–	
Turn−on switching loss		E_{on}	–	0.75	–	mJ
Turn−off switching loss		E_{off}	–	0.29	–	
Total switching loss		E_{ts}	–	1.04	–	

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ELECTRICAL CHARACTERISTICS (T_J = 25°C unless otherwise noted) (Continued)

Parameter	Test Conditions	Symbol	Min	Typ	Max	Unit
SWITCHING CHARACTERISTICS, INDUCTIVE LOAD						
Turn−on delay time	T_J = 175°C, V_{CC} = 400 V, I_C = 20 A, R_G = 6 Ω, V_{GE} = 15 V, Inductive Load, FWD: AFGHL40T65SQD	$t_{d(on)}$	−	14	−	ns
Rise time		t_r	−	12	−	
Turn−off delay time		$t_{d(off)}$	−	81	−	
Fall time		t_f	−	7	−	
Turn−on switching loss		E_{on}	−	0.46	−	mJ
Turn−off switching loss		E_{off}	−	0.22	−	
Total switching loss		E_{ts}	−	0.68	−	
Turn−on delay time	T_J = 175°C, V_{CC} = 400 V, I_C = 40 A, R_G = 6 Ω, V_{GE} = 15 V, Inductive Load, FWD: AFGHL40T65SQD	$t_{d(on)}$	−	16	−	ns
Rise time		t_r	−	25	−	
Turn−off delay time		$t_{d(off)}$	−	75	−	
Fall time		t_f	−	38	−	
Turn−on switching loss		E_{on}	−	1.06	−	mJ
Turn−off switching loss		E_{off}	−	0.47	−	
Total switching loss		E_{ts}	−	1.53	−	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

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TYPICAL CHARACTERISTICS

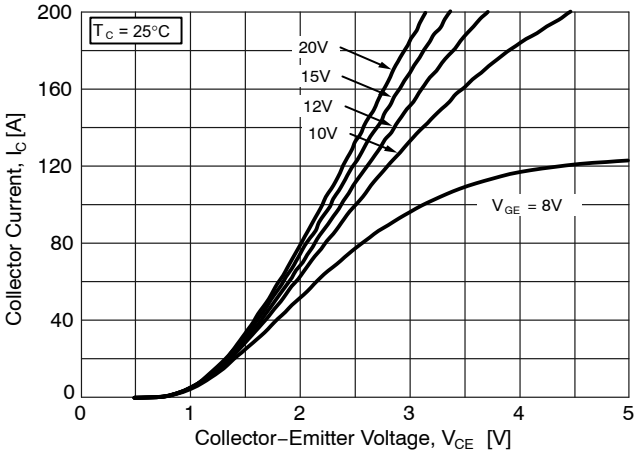


Figure 1. Typical Output Characteristics

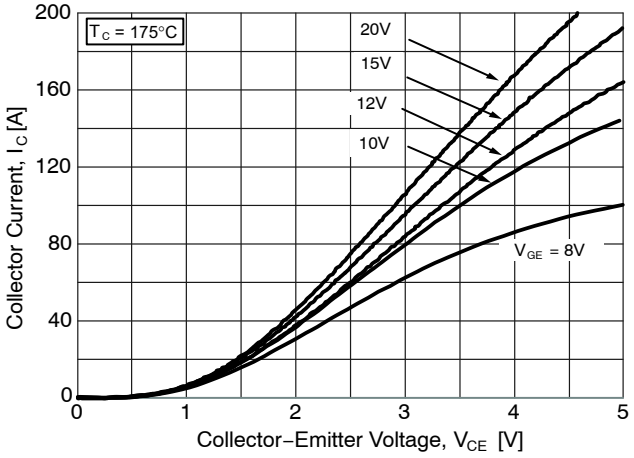


Figure 2. Typical Output Characteristics

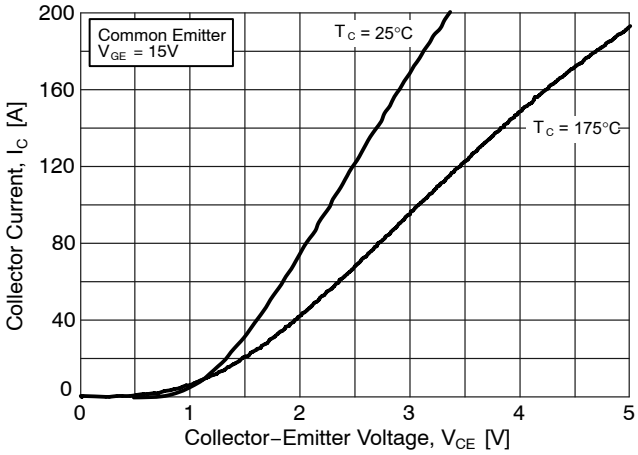


Figure 3. Typical Saturation Voltage

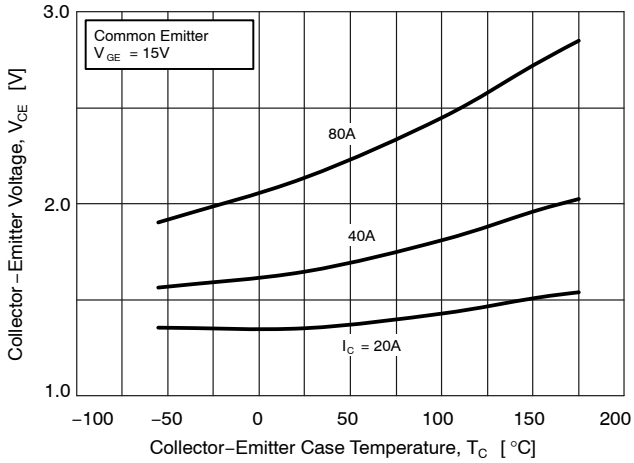


Figure 4. Saturation Voltage vs. Case Temperature

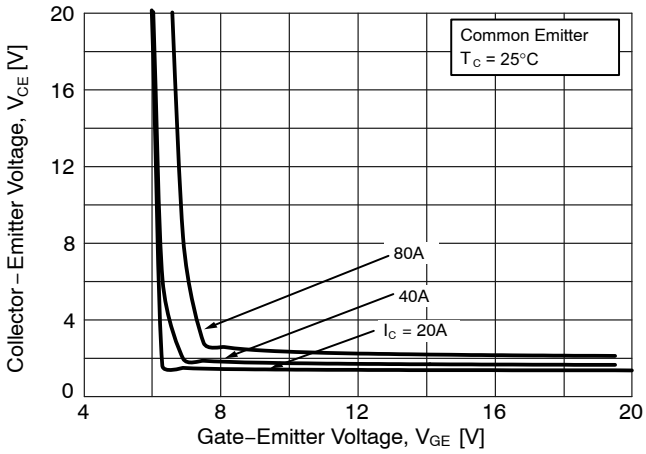


Figure 5. Saturation Voltage vs. V_{GE}

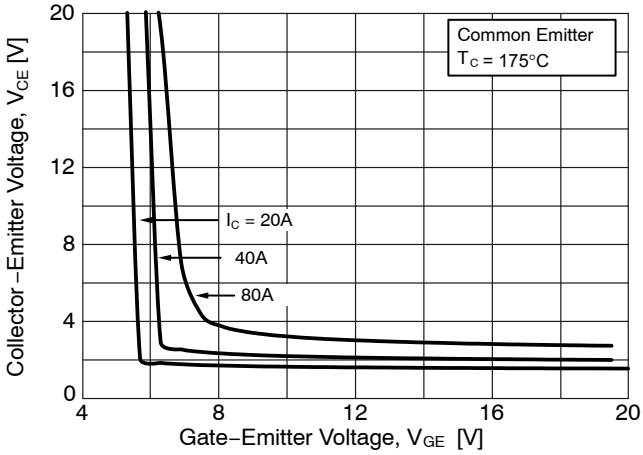


Figure 6. Saturation Voltage vs. V_{GE}

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TYPICAL CHARACTERISTICS

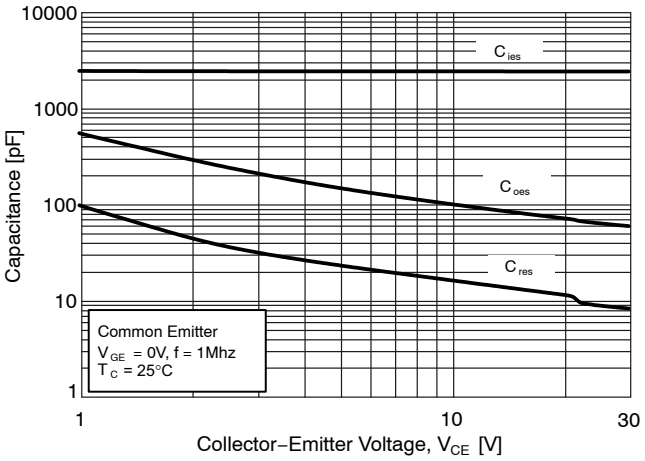


Figure 7. Capacitance Characteristics

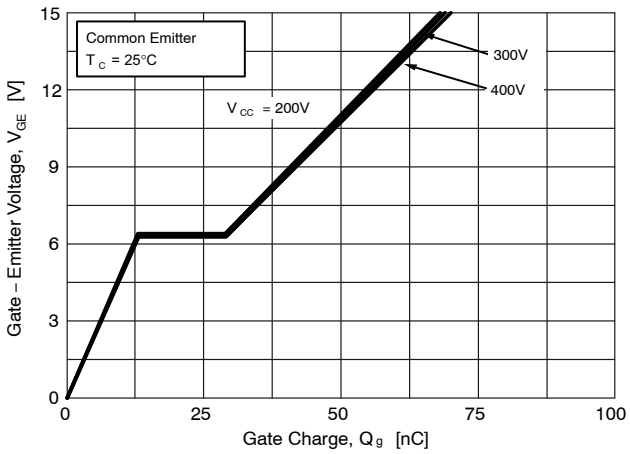


Figure 8. Gate Charge

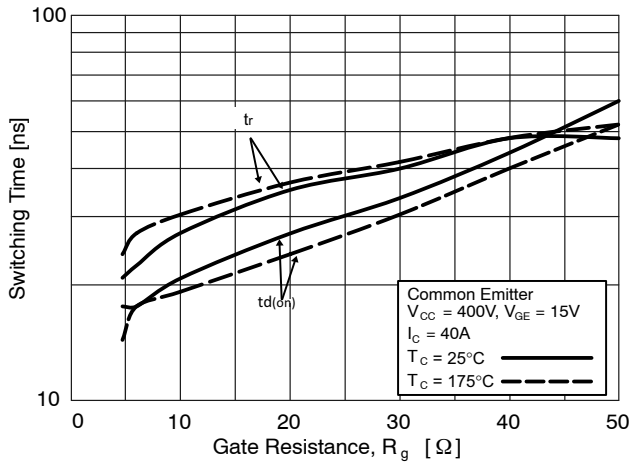


Figure 9. Turn−On Characteristics vs. Gate Resistance

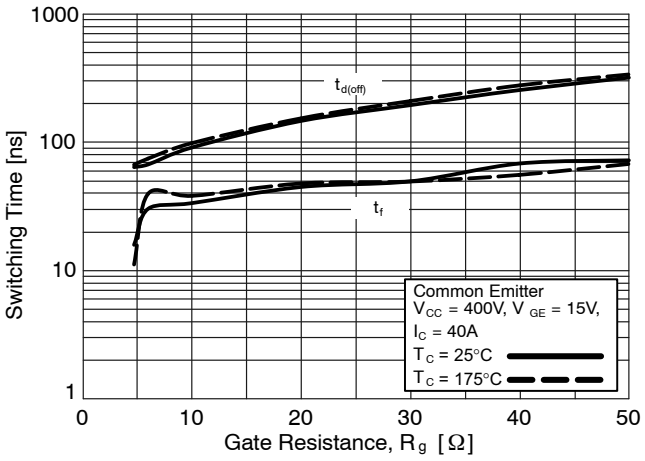


Figure 10. Turn−Off Characteristics vs. Gate Resistance

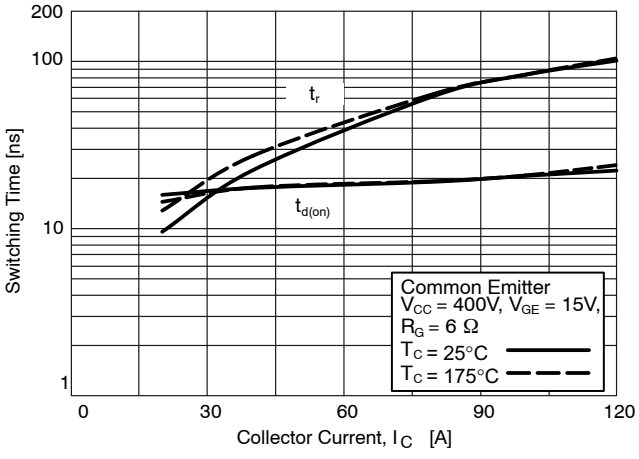


Figure 11. Turn−On Characteristics vs. Collector Current

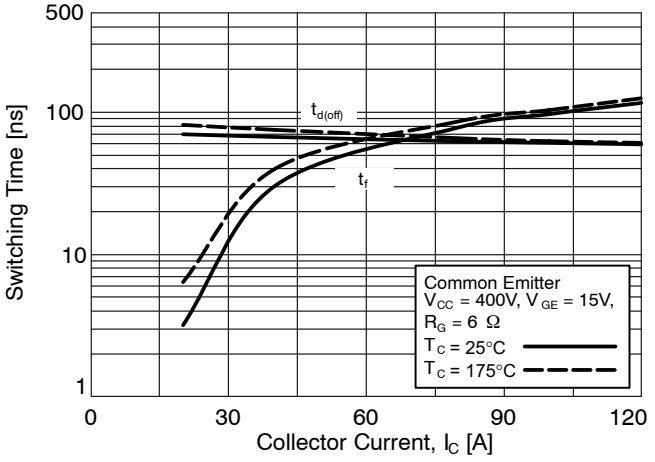


Figure 12. Turn−Off Characteristics vs. Collector Current

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TYPICAL CHARACTERISTICS

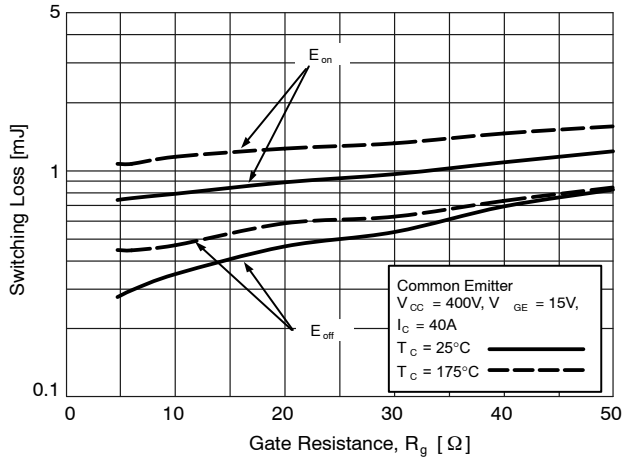


Figure 13. Switching Loss vs. Gate Resistance

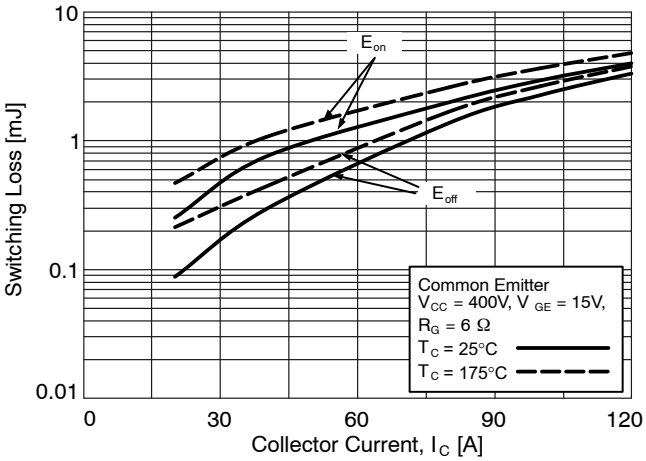


Figure 14. Switching Loss vs. Collector Current

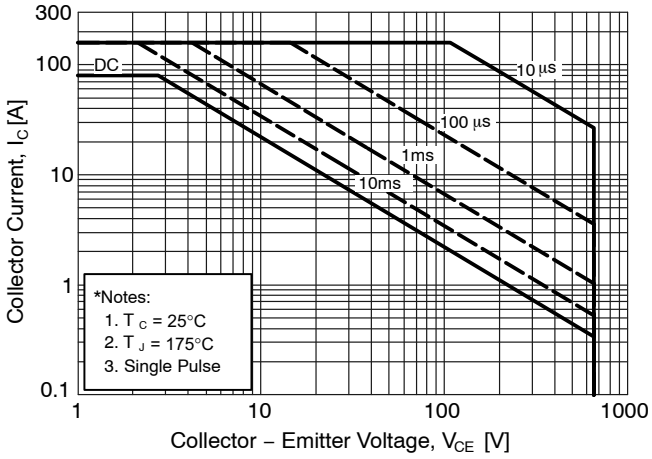


Figure 15. SOA Characteristics

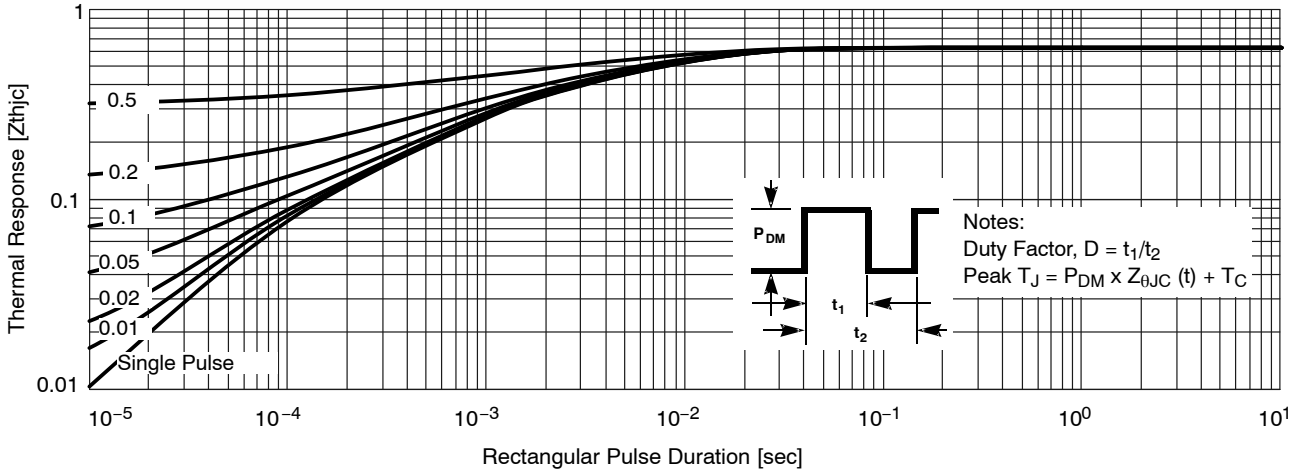
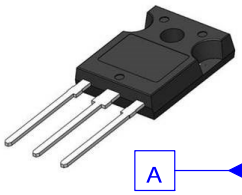


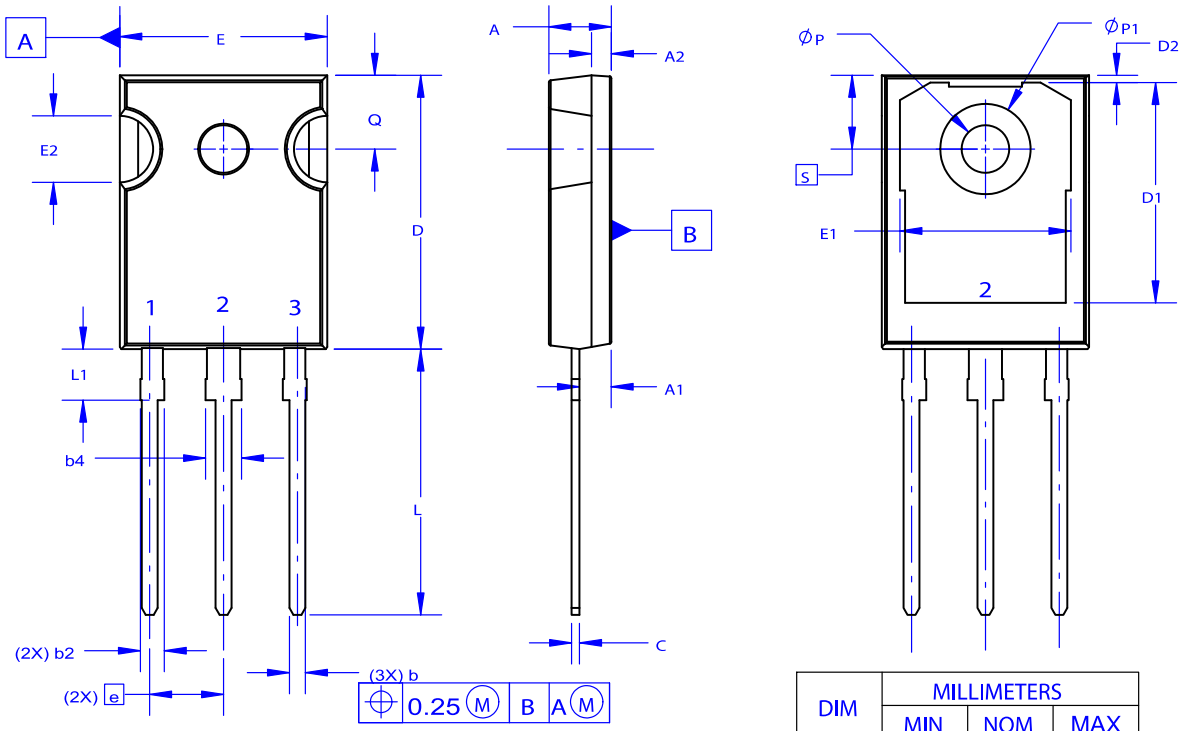
Figure 16. transient Thermal Impedance of IGBT

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TO−247−3LD
CASE 340CX
ISSUE A

DATE 06 JUL 2020





NOTES: UNLESS OTHERWISE SPECIFIED.

A. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.
B. ALL DIMENSIONS ARE IN MILLIMETERS.
C. DRAWING CONFORMS TO ASME Y14.5 - 2009.
D. DIMENSION A1 TO BE MEASURED IN THE REGION DEFINED BY L1.
E. LEAD FINISH IS UNCONTROLLED IN THE REGION DEFINED BY L1.

DIM	MILLIMETERS		
	MIN	NOM	MAX
A	4.58	4.70	4.82
A1	2.20	2.40	2.60
A2	1.40	1.50	1.60
D	20.32	20.57	20.82
E	15.37	15.62	15.87
E2	4.96	5.08	5.20
e	~	5.56	~
L	19.75	20.00	20.25
L1	3.69	3.81	3.93
ØP	3.51	3.58	3.65
Q	5.34	5.46	5.58
S	5.34	5.46	5.58
b	1.17	1.26	1.35
b2	1.53	1.65	1.77
b4	2.42	2.54	2.66
c	0.51	0.61	0.71
D1	13.08	~	~
D2	0.51	0.93	1.35
E1	12.81	~	~
ØP1	6.60	6.80	7.00

GENERIC MARKING DIAGRAM*



XXXXX = Specific Device Code
A = Assembly Location
Y = Year
WW = Work Week
G = Pb−Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb−Free indicator, “G” or microdot “ ▪”, may or may not be present. Some products may not follow the Generic Marking.

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Teklif isteyin

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